AT45DB041E



4-Mbit, 1.65V Minimum SPI DataFlash® Memory

DATASHEET (ADDENDUM)

High Temperature Operation (125°C)

This data sheet addendum is to be used in conjunction with the existing AT45DB041E datasheet specifications. The Adesto AT45DB041E 4Mbit DataFlash devices will operate @ 125°C with the following datasheet caveats. All other parameters will meet the existing datasheet specifications.

The ordering code suffix (CAN# Code) 'HT' must be used to ensure correct operation at this extended temperature range. Adesto will not modify and republish the current datasheet to reflect the CAN# 'HT' ordering code or the above caveats. The standard AT45DB041E datasheet is available at http://www.adestotech.com.

1. Electrical Specifications

1.1 DC and AC Operating Range

	AT45DB041E-xxxHT
Operating Temperature	-40°C to +125°C
Endurance (Maximum)	10,000 Cycles

1.2 DC Characteristics

			1.65V to 3.6V		2.3V to 3.6V				
Symbol	Parameter	Condition	Min	Тур	Max	Min	Тур	Max	Units
I _{DPD}	Deep Power-Down Current	CS, RESET, WP = V _{IH} All inputs at CMOS levels		4.5	20		5	20	μΑ
I _{SB}	Standby Current	CS, RESET, WP = V _{IH} All inputs at CMOS levels		25	45		25	45	μΑ
I _{CC3}	Active Current, Program Operation	CS=V _{CC}		14	20		14	20	mA

1.3 AC Characteristics

		1.65V to 3.6V		2.3V to 3.6V		
Symbol	Parameter	Min	Max	Min	Max	Units
f _{CAR1}	SCK Frequency for Continuous Read (0x0B)		70		70	MHz
f _{CAR2}	SCK Frequency for Continuous Read (0x03) (Low Frequency)		33		33	MHz
t _{CS}	Minimum CS High Time	24		24		ns
t _V	Output Valid		8		6	ns

1.4 Program and Erase Characteristics

		1.65V to 3.6V		2.3V to 3.6V		
Symbol	Parameter	Тур	Max	Тур	Max	Units
t _{BE}	Block Erase Time	30	50	30	50	ms
t _{SE}	Sector Erase Time	.7	1.3	.7	1.3	S

Notes: 1. Values are based on device characterization, not 100% tested in production.

2. Not 100% tested (value guaranteed by design and characterization).

2. Ordering Code

2.1 Ordering Code Detail

Ordering Code ⁽¹⁾	Package	Operating Voltage	Max. Freq. (MHz)	Operation Range		
AT45DB041E-SHNHT-T	000	1.65V to 3.6V	85MHz			
AT45DB041E-SHNHT-B	8S2 8S1			Extended		
AT45DB041E-SSHNHT-T		1.050 to 5.00	OSIVITZ	(-40°C to +125°C)		
AT45DB041E-SSHNHT-B	001					

^{1.} The shipping carrier option code is not marked on the devices.

Package Type				
8S1 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)				
8S2	8-lead, 0.208" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)			

1. Revision History

Revision Level – Release Date	History
A – January 2015	Initial release.
B – October 2015	Corrected package type in Ordering Code Detail table.
C – August 2017	Updated corporate address information.



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